

Description

The HCJU30P10 uses advanced trench technology

to provide excellent R_{DS(ON)}, low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

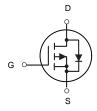
Battery protection or in other Switching application.



General Features

 $V_{DS} = -100V I_{D} = -30A$

 $R_{DS(ON)} < 57.5~m\Omega$ @ $V_{GS} = -10V$



Application

Battery protection

Load switch

Uninterruptible power supply

P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HCJU30P10	TO-252-2L	30P10 XXXX	2500

Absolute Maximum Ratings (T_c=25[°]Cunless otherwise noted)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	-100	V
VGS	Gate-Source Voltage	±20	٧
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	-30	Α
IDM	Pulsed Drain Current ²	-120	А
P _D @T _C =25°C	Total Power Dissipation ⁴	107	W
Eas	Avalanche energy (Note 2)	361	mJ
TSTG	Storage Temperature Range -55 to 175		°C
TJ	Operating Junction Temperature Range -55 to 175		°C
R₀JC	Thermal Resistance Junction-Case ¹	1.4	°C/W



Electrical Characteristics (T = 25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V I _D =-250μA	-100	-127		V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =-100V, V _{GS} =0V			-1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V			±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.8	-2.5	V
g FS	Forward Transconductance	V _{DS} =-5V, I _D =-15A		50		S
D	D : 0 0 0 1 D : 1	V _{GS} =-10V, I _D =-15A		46	57.5	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} =-4.5V, I _D =-10A		48	63	mΩ
Ciss	Input Capacitance			8056		pF
Coss	Output Capacitance	V _{DS} =-25V, V _{GS} =0V, f=1.0MHz		195		pF
Crss	Reverse Transfer Capacitance			70		pF
t _{d(on)}	Turn-on Delay Time			13		nS
t r	Turn-on Rise Time	V _{GS} =-10V, V _{DS} =-50V,		64		nS
$t_{d(off)}$	Turn-Off Delay Time	R_L =3.3Ω, R_{GEN} =9.1Ω		36		nS
t _f	Turn-Off Fall Time			52		nS
Qg	Total Gate Charge			147		nC
Qgs	Gate-Source Charge	V _{GS} =-10V, V _{DS} =-50V, I _D =-10A		17		nC
Q_{gd}	Gate-Drain Charge			31		nC
I _{SD}	Source-Drain Current (Body Diode)				-30	Α
V _{SD}	Forward on Voltage (Note 3)	V _{GS} =0V, I _S =-15A			-1.2	V
t _{rr}	Reverse Recovery Time	I _F =-15A, di/dt=100A/μs		72		ns
Qrr	Reverse Recovery Charge	I _F =-15A, di/dt=100A/μs		120		nC

Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature. Notes 2.E_{AS} condition: T_J=25 $^{\circ}$ C,V_{DD}=50V,V_G=-10V, Rg=25 $^{\circ}$ L=0.5mH.

Notes 3.Repetitive Rating: Pulse width limited by maximum junction temperature.



Typical Characteristics

Figure 1. Output Characteristics

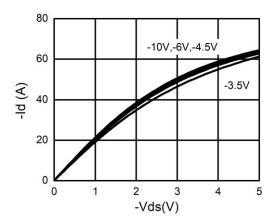


Figure 3. Power Dissipation

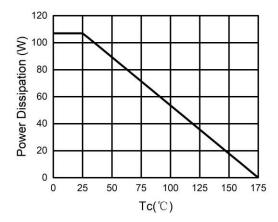


Figure 5. BV_{DSS} vs Junction Temperature

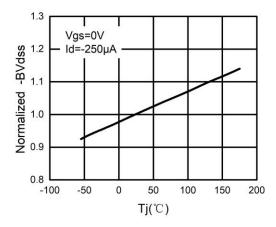


Figure 2. Transfer Characteristics

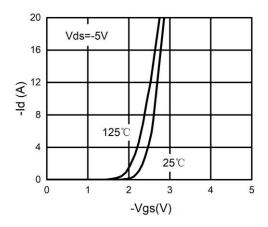


Figure 4. Drain Current

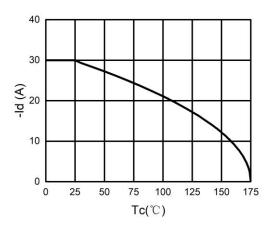


Figure 6. R_{DS(ON)} vs Junction Temperature

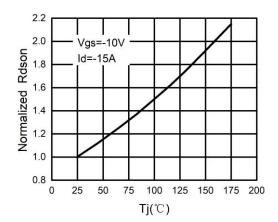




Figure 7. Gate Charge Waveforms

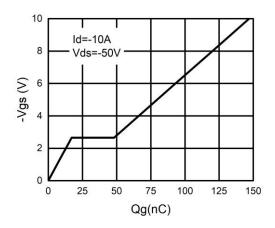


Figure 8. Capacitance

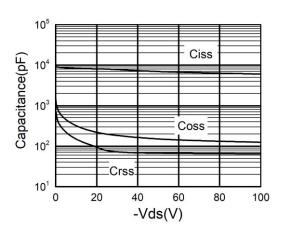


Figure 9. Body-Diode Characteristics

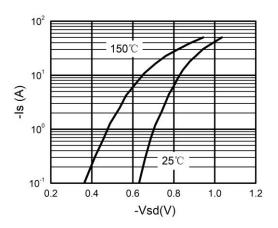
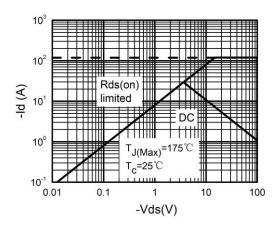


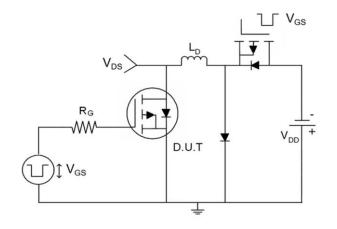
Figure 10. Maximum Safe Operating Area

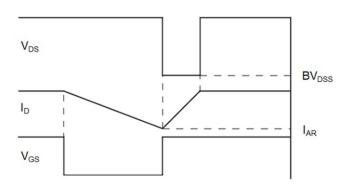




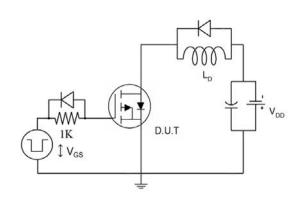
Test Circuit

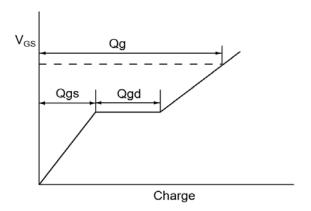
1) E_{AS} Test Circuits



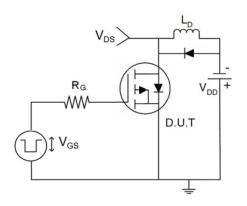


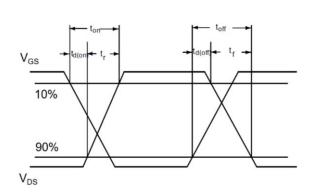
2) Gate Charge Test Circuit





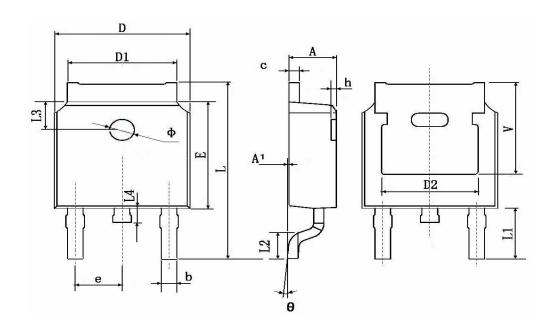
3) Switch Time Test Circuit







TO-252-2L Package Information



Dimensions In Millimeters		Dimensions In Inches		
Min.	Max.	Min.	Max.	
2.200	2.400	0.087	0.094	
0.000	0.127	0.000	0.005	
0.660	0.860	0.026	0.034	
0.460	0.580	0.018	0.023	
6.500	6.700	0.256	0.264	
5.100	5.460	0.201	0.215	
4.830 TYP.		0.190 TYP.		
6.000	6.200	0.236	0.244	
2.186	2.386	0.086	0.094	
9.800	10.400	0.386	0.409	
2.900 TYP.		0.114 TYP.		
1.400	1.700	0.055	0.067	
	1.600 TYP.		0.063 TYP.	
0.600	1.000	0.024	0.039	
1.100	1.300	0.043	0.051	
0°	8°	0°	8°	
0.000	0.300	0.000	0.012	
5.350	0 TYP. 0.211 TYP.		TYP.	
	Min. 2.200 0.000 0.660 0.460 6.500 5.100 4.830 6.000 2.186 9.800 2.900 1.400 1.600 0.600 1.100 0° 0.000	Min. Max. 2.200 2.400 0.000 0.127 0.660 0.860 0.460 0.580 6.500 6.700 5.100 5.460 4.830 TYP. 6.000 2.186 2.386 9.800 10.400 2.900 TYP. 1.700 1.600 TYP. 1.000 1.100 1.300 0° 8°	Min. Max. Min. 2.200 2.400 0.087 0.000 0.127 0.000 0.660 0.860 0.026 0.460 0.580 0.018 6.500 6.700 0.256 5.100 5.460 0.201 4.830 TYP. 0.190 6.000 6.200 0.236 2.186 2.386 0.086 9.800 10.400 0.386 2.900 TYP. 0.114 1.400 1.700 0.055 1.600 TYP. 0.063 0.600 1.000 0.024 1.100 1.300 0.043 0° 8° 0° 0.000 0.300 0.000	

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